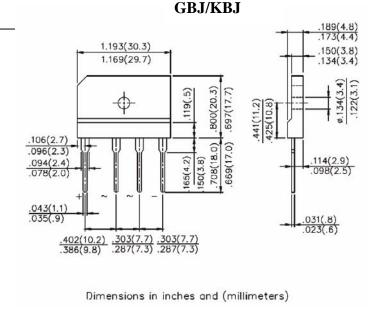


SINGLE-PHASE SILICON BRIDGE KBJ25005 thru KBJ2510 50 to 1000 V 25.0 A

FEATURES

- Low leakage
- Low forward voltage
- Mounting Position: Any
- Surge overload rating:300 amperes peak
- Siliver-plated copper leads



Maximum Ratings and Electrical Characteristics

Ratings at 25° C ambient temperature unless otherwise specified. Single phase , half wave, 60HZ, resistive or inductive load. For capacitive load, derate current by 20%.

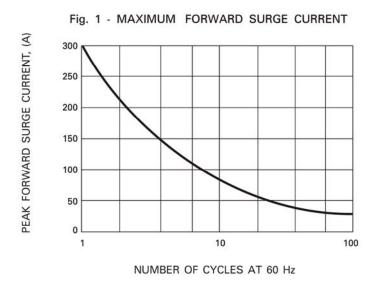
MAXIMUM RATINGS(At Ta=25°C unless otherwise noted)

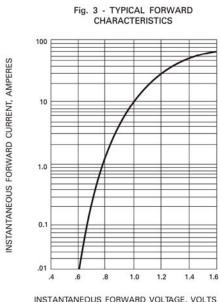
RATINGS	Symbol	KBJ25005	KBJ2501	KBJ2502	KBJ2504	KBJ2506	KBJ2508	KBJ2510	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at @ $T_C = 50^{\circ}C$	Io	25							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}	300							Amp
Maximum Forward Voltage drop per element of 12.5A DC	V _F	1.1							Volts
Maximum DC Reverse Current at rated @ T _A =25°C	I _R	10							μ Amp
Operating Temperature Range	$T_{\rm J}$	-55 to +150							°C
Storage Temperature Range	T _{STG}	-55 to +150							$^{\circ}$



SINGLE-PHASE SILICON BRIDGE KBJ25005 thru KBJ2510 50 to 1000 V 25.0 A

RATINGS AND CHARACTERISTIC CURVES (KBJ25005 thru KBJ2510)





INSTANTANEOUS FORWARD VOLTAGE, VOLTS

Fig. 4 - TYPICAL REVERSE

